



VOLTAGE MODE DUAL OUTPUT PWM CONTROLLER

Description

The DIODES™ AZ494 is a voltage mode pulse width modulation switching regulator control circuit designed primarily for power supply control.

amplifiers, an on-chip adjustable oscillator, a dead-time control (DTC) comparator, a pulse-steering control flip-flop, and an output control circuit. The precision of voltage reference (VREF) is improved up to ±1% through trimming and this provides a better output voltage regulation. The AZ494 provides for push-pull or single-ended output operation, which can be selected through the output control.

The difference between AZ494A and AZ494C is that they have 4.95V and 5V reference voltage respectively.

The AZ494 is available in standard packages of PDIP-16 and SO-16.

Pin Assignments



1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS) & 2011/65/EU (RoHS 2) compliant. Notes:

- See http://www.diodes.com/quality/lead_free.html for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.
- 3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.



Output Function Control Table

Signal for Output Control	Output Function				
V _I = GND	Single-ended or parallel output				
Vi = V _{REF}	Normal push-pull operation				
Typical Applications Circuit					
(V _I =10V to 40V) KSA1010	1mH (V ₀ =5V, I ₀ =1A) 2A				
$V_{1}(+) \bigcirc 47 \\ 150 & 0.1\mu = 11 \\ 12 & 11 & 8 & 3 \\ V_{CC} & C2 & C1 & FEED \\ BACK \\ + 50\mu \\ 50V \\ AZ494 \\ 0UTPUT \\ DTC & GND & E1 & CONTROL & E2 & RT \\ 4 & 7 & 9 & 13 & 10 & 6 \\ \hline \end{array}$	$ \begin{array}{c} 2 \\ 1 \text{IN-} \\ \text{REF} \\ 2 \text{IN-} \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1 \\ 1$				
	→				
Vi(-)					

Pulse Width Modulated Step-Down Converter



Functional Block Diagram



Absolute Maximum Ratings (Note 4)

Symbol	Parameter	Ra	ting	Unit
Vcc	Supply Voltage (Note 5)	40		V
VI	Amplifier Input Voltage	-0.3 to \	/ _{CC} + 0.3	V
Vo	Collector Output Voltage		40	V
lo	Collector Output Current	2	50	mA
		M Package	73	°C/W
θја	Package Thermal Impedance (Note 6)	P Package	67	C/W
	Lead Temperature 1.6mm from case for 10 seconds	+260		°C
T _{STG}	Storage Temperature Range	-65 to +150		°C
_	ESD Rating (Machine Model)	200		V

- Notes: 4. Stresses greater than those listed under "Absolute Maximum Ratings" may cause permanent damage to the device. These are stress ratings only, and functional operation of the device at these or any other conditions beyond those indicated under "Recommended Operating Conditions" is not implied. Exposure to "Absolute Maximum Ratings" for extended periods may affect device reliability.
 - 5. All voltage values are with respect to the network ground terminal.
 - 6. Maximum power dissipation is a function of $T_J(max)$, θ_{JA} and T_A . The maximum allowable power dissipation at any allowable ambient temperature is $P_D = (T_J(max) T_A)/\theta_{JA}$. Operating at the absolute maximum T_J of +150°C can affect reliability.



Recommended Operating Conditions

Symbol	Parameter	Min	Тур	Max	Unit			
V _{CC}	Supply Voltage	7	15	36	V			
V _{C1} , V _{C2}	Collector Output Voltage	-	30	36	V			
I_{C1}, I_{C2}	Collector Output Current(Each Transistor)	-	-	200	mA			
VI	Amplifier Input Voltage	0.3	-	V _{CC} - 2	V			
I _{FB}	Current Into Feedback Terminal	-	-	0.3	mA			
I _{REF}	Reference Output Current	-		10	mA			
CT	Timing Capacitor	0.00047	0.001	10	μF			
RT	Timing Resistor	1.8	30	500	kΩ			
f _{osc}	Oscillator Frequency	1.0	40	200	kHz			
_	PWM Input Voltage (Pin 3, 4, 14)	0.3	-	5.3	V			
TA	Operating Free-Air Temperature	-40	E	+85	°C			

Electrical Characteristics (T_A=+25°C, V_{CC}=20V, f=10kHz, unless otherwise noted.)

Symbol Parameter		Conditions	Min	Тур	Max	Unit	
Reference Sectio	n		-		-	-	
\/	Output Reference Voltage	I _{REF} =1mA	4.90	4.95	5.0	V	
V _{REF}	for AZ494A	I _{REF} =1mA, T _A = -40 to +85°C	4.85	4.95	5.05	V	
\/	Output Reference Voltage	I _{REF} =1mA	4.95	5.0	5.05	V	
V _{REF}	for AZ494C	I _{REF} =1mA, T _A = -40 to +85°C		5.0	5.1	V	
RLINE	Line Regulation	V _{CC} = 7V to 36V	-	2	25	mV	
R _{LOAD}	Load Regulation	I _{REF} =1mA to 10mA	-	1	15	mV	
Isc	Short-Circuit Output Current	V _{REF} = 0V	10	35	50	mA	
Oscillator Section	1	-	-				
		C _T =0.001μF, R _T =30kΩ	-	40	_	- kHz	
fosc	Oscillator Frequency	$C_T=0.01\mu F, R_T=12k\Omega$	9.2	10	10.8		
.030		C _T =0.01μF, R _T =12kΩ T _A = -40 to +85°C	9.0	_	12		
$\Delta f / \Delta T$	Frequency Change with Temperature	C _T =0.01μF, R _T =12kΩ T _A = -40 to +85°C	_	_	1	%	



Electrical Characteristics (T_A=+25°C, V_{CC}=20V, f=10kHz unless otherwise noted.) (Cont.)

Symbol	Parame	ter	Conditions	Min	Тур	Max	Unit		
Dead-Time Control Section									
I _{BIAS}	Input Bias Current		V_{CC} =15V, V_{PIN4} = 0 to 5.25V	_	-2	-10	μΑ		
D(MAX)	Maximum Duty Cycl	е	V _{CC} =15V, V _{PIN4} = 0V, V _{PIN13} = V _{REF}	45	-	_	%		
V _{ITH}	Input Threshold Volt	200	Zero Duty Cycle	-	3	3.3	V		
VITH	input miesnoid voit	aye	Maximum Duty Cycle	0	0		V		
Error-Amplifier Section									
VIO	Input Offset Voltage		V _{PIN3} = 2.5V	-	2	10	mV		
I _{IO}	Input Offset Current		V _{PIN3} = 2.5V	-	25	250	nA		
I _{BIAS}	Input Bias Current		V _{PIN3} = 2.5V		0.2	1	μА		
V _{CM}	Common-Mode Inpu Range	it Voltage	V _{CC} =7V to 36V	-0.3		Vcc-2	V		
Gvo	Open-Loop Voltage	Gain	V _O =0.5V to 3.5V	70	95	_	dB		
BW	Unity-Gain Bandwid	th	-		650	_	kHz		
CMRR	Common-Mode Rejection Ratio		-	65	80	_	dB		
Isink	Output Sink Current (Feedback)		V _{ID} = -15mV to -5V, V3 = 0.7V -0.3		-0.7	_	mA		
ISOURCE	Output Source Current (Feedback)		V_{ID} =15mV to 5V, V3 = 3.5V	2	-	-	mA		
PWM Comparate	or Section								
V _{ITH}	Input Threshold Voltage		Zero duty cycle	-	4	4.5	V		
I _{SINK}	Input Sink Current		V3 = 0.7V	-0.3	-0.7	-	mA		
Output Section									
V _{CE} (SAT)	Output Saturation	Common Emitter	V _E = 0V, I _C =200mA	-	1.1	1.3			
V _{CC} (SAT)	Voltage	Emitter Follower	Vcc = 15V, IE = -200mA	-	1.5	2.5	V		
I _C (OFF)	Collector Off-State Current		V _{CE} = 36V, V _{CC} =36V	-	2	100	μΑ		
I _E (OFF)	Emitter Off-State Current		$V_{CC} = V_C = 36V, V_E = 0$		_	-100	μΑ		
Total Device									
lcc	Supply Current		$V_{PIN6} = V_{REF}, V_{CC} = 15V$	-	6	10	mA		
Output Switchin	g Characteristics								
t _R	Rise Time		Common Emitter Common Collector	-	100	200	ns		
t _F	Fall Time		Common Emitter Common Collector	-	25	100	ns		



Parameter Measurement Information







Parameter Measurement Information (Cont.)



Note A: C_L includes probe and jig capacitance.





Performance Characteristics





Marking Information

PDIP-16 (Top View)





Package Outline Dimensions (All dimensions in mm(inch).)

(1) Package Type: SO-16



Note: Eject hole, oriented hole and mold mark is optional.

-									
	Symbol		C)			D	1	
	Cymbol	min(mm)	max(mm)	min(inch)	max(inch)	min(mm)	max(mm)	min(inch)	max(inch)
	Option1	1.350	1.750	0.053	0.069	1.250	1.650	0.049	0.065
	Option2	-	1.260	-	0.050	1.020	-	0.040	-



Package Outline Dimensions (All dimensions in mm(inch).) (Cont.)

(2) Package Type: PDIP-16



Note: Eject hole, oriented hole and mold mark is optional.



Suggested Pad Layout

(1) Package Type: SO-16





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